

# 3.3 V/5 V ECL Differential Receiver/Driver with High Gain

## MC100EP16VA

### Description

The EP16VA is a world-class differential receiver/driver. The device is functionally equivalent to the EP16 and LVEP16 devices but with high gain output.  $Q_{HG}$  and  $\overline{Q}_{HG}$  outputs have a DC gain several times larger than the DC gain of an EP16.

The  $V_{BB}$  pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to  $V_{BB}$  as a switching reference voltage.  $V_{BB}$  may also rebias AC coupled inputs. When used, decouple  $V_{BB}$  and  $V_{CC}$  via a 0.01  $\mu$ F capacitor and limit current sourcing or sinking to 0.5 mA. When not used,  $V_{BB}$  should be left open.

Under open input conditions (pulled to  $V_{EE}$ ) internal input clamps will force the  $Q_{HG}$  output LOW.

Special considerations are required for differential inputs under No Signal conditions to prevent instability.

The 100 Series contains temperature compensation.

### Features

- 270 ps Typical Propagation Delay
- Gain = > 20
- 20 mV Minimum Input Voltage Swing
- Maximum Frequency = > 3 GHz Typical
- PECL Mode Operating Range:  
 $V_{CC} = 3.0$  V to 5.5 V with  $V_{EE} = 0$  V
- NECL Mode Operating Range:  
 $V_{CC} = 0$  V with  $V_{EE} = -3.0$  V to  $-5.5$  V
- Open Input Default State
- $V_{BB}$  Output
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



ON Semiconductor®

[www.onsemi.com](http://www.onsemi.com)

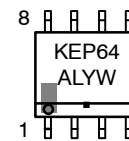


SOIC-8 NB  
D SUFFIX  
CASE 751-07

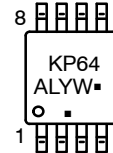


TSSOP-8  
DT SUFFIX  
CASE 948R-02

### MARKING DIAGRAMS\*



SOIC-8 NB



TSSOP-8

K = MC100  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

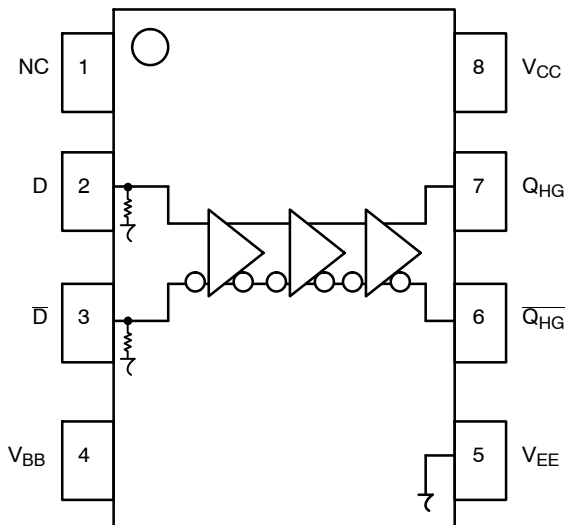
\*For additional marking information, refer to Application Note [AND8002/D](#).

### ORDERING INFORMATION

| Device           | Package                | Shipping†             |
|------------------|------------------------|-----------------------|
| MC100EP16VADG    | SOIC-8 NB<br>(Pb-Free) | 98 Units /<br>Tube    |
| MC100EP16VADTG   | TSSOP-8<br>(Pb-Free)   | 100 Units /<br>Tube   |
| MC100EP16VADTR2G | TSSOP-8<br>(Pb-Free)   | 2500 /<br>Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

# MC100EP16VA



**Table 1. PIN DESCRIPTION**

| PIN                            | FUNCTION                   |
|--------------------------------|----------------------------|
| D*, $\overline{D}^*$           | ECL Data Inputs            |
| $Q_{HG}$ , $\overline{Q}_{HG}$ | ECL High Gain Data Outputs |
| V <sub>BB</sub>                | Reference Voltage Output   |
| V <sub>CC</sub>                | Positive Supply            |
| V <sub>EE</sub>                | Negative Supply            |
| NC                             | No Connect                 |

\* Pins will default LOW when left open.

**Figure 1. 8-Lead Pinout (Top View) and Logic Diagram**

**Table 2. ATTRIBUTES**

| Characteristics   | Value                       |
|---|-----------------------------|
| Internal Input Pulldown Resistor  | 75 k $\Omega$               |
| Internal Input Pullup Resistor  | N/A                         |
| ESD Protection<br>Human Body Model<br>Machine Model<br>Charged Device Model | > 4 kV<br>> 200 V<br>> 2 kV |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)               | Pb-Free Pkg                 |
| SOIC-8 NB<br>TSSOP-8  | Level 1<br>Level 3          |
| Flammability Rating<br>Oxygen Index: 28 to 34                               | UL-94 V-0 @ 0.125 in        |
| Transistor Count  | 167                         |
| Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test                      |                             |

1. For additional information, see Application Note [AND8003/D](#).

# MC100EP16VA

**Table 3. MAXIMUM RATINGS**

| Symbol        | Parameter  | Condition 1                                    | Condition 2                            | Rating      | Unit |
|---------------|--|--|--|-------------|------|
| $V_{CC}$      | PECL Mode Power Supply                             | $V_{EE} = 0\text{ V}$                          |  | 6           | V    |
| $V_{EE}$      | NECL Mode Power Supply                             | $V_{CC} = 0\text{ V}$                          |  | -6          | V    |
| $V_I$         | PECL Mode Input Voltage<br>NECL Mode Input Voltage | $V_{EE} = 0\text{ V}$<br>$V_{CC} = 0\text{ V}$ | $V_I \leq V_{CC}$<br>$V_I \geq V_{EE}$ | 6<br>-6     | V    |
| $I_{out}$     | Output Current                                     | Continuous<br>Surge                            |  | 50<br>100   | mA   |
| $I_{BB}$      | $V_{BB}$ Sink/Source                               |  |  | $\pm 0.5$   | mA   |
| $T_A$         | Operating Temperature Range                        |  |  | -40 to +85  | °C   |
| $T_{stg}$     | Storage Temperature Range                          |  |  | -65 to +150 | °C   |
| $\theta_{JA}$ | Thermal Resistance (Junction-to-Ambient)           | 0 lfpm<br>500 lfpm                             | SOIC-8 NB<br>SOIC-8 NB                 | 190<br>130  | °C/W |
| $\theta_{JC}$ | Thermal Resistance (Junction-to-Case)              | Standard Board                                 | SOIC-8 NB                              | 41 to 44    | °C/W |
| $\theta_{JA}$ | Thermal Resistance (Junction-to-Ambient)           | 0 lfpm<br>500 lfpm                             | TSSOP-8<br>TSSOP-8                     | 185<br>140  | °C/W |
| $\theta_{JC}$ | Thermal Resistance (Junction-to-Case)              | Standard Board                                 | TSSOP-8                                | 41 to 44    | °C/W |
| $T_{sol}$     | Wave Solder (Pb-Free)                              | < 2 to 3 sec @ 260°C                           |  | 265         | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. JEDEC standard multilayer board – 2S2P (2 signal, 2 power)

# MC100EP16VA

**Table 4. 100EP DC CHARACTERISTICS, PECL** ( $V_{CC} = 3.3\text{ V}$ ,  $V_{EE} = 0\text{ V}$  (Note 1))

| Symbol      | Characteristic   | -40°C |      |      | 25°C |      |      | 85°C |      |      | Unit          |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
|             |  | Min   | Typ  | Max  | Min  | Typ  | Max  | Min  | Typ  | Max  |               |
| $I_{EE}$    | Power Supply Current   | 22    | 28   | 36   | 24   | 30   | 40   | 26   | 32   | 42   | mA            |
| $V_{OH}$    | Output HIGH Voltage (Note 2)   | 2155  | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | mV            |
| $V_{OL}$    | Output LOW Voltage (Note 2)  | 1305  | 1430 | 1555 | 1305 | 1430 | 1555 | 1305 | 1430 | 1555 | mV            |
| $V_{IH}$    | Input HIGH Voltage (Single-Ended)  | 2075  |      | 2420 | 2075 |      | 2420 | 2075 |      | 2420 | mV            |
| $V_{IL}$    | Input LOW Voltage (Single-Ended)   | 1355  |      | 1675 | 1355 |      | 1675 | 1355 |      | 1675 | mV            |
| $V_{BB}$    | Output Voltage Reference   | 1775  | 1875 | 1975 | 1775 | 1875 | 1975 | 1775 | 1875 | 1975 | mV            |
| $V_{IHCMR}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0   |      | 3.3  | 2.0  |      | 3.3  | 2.0  |      | 3.3  | V             |
| $I_{IH}$    | Input HIGH Current   |       |      | 150  |      |      | 150  |      |      | 150  | $\mu\text{A}$ |
| $I_{IL}$    | Input LOW Current  | 0.5   |      |      | 0.5  |      |      | 0.5  |      |      | $\mu\text{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with  $V_{CC}$ .  $V_{EE}$  can vary +0.3 V to -2.2 V.
2. All loading with 50  $\Omega$  to  $V_{CC} - 2.0\text{ V}$ .
3.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ .  $V_{IHCMR}$  max varies 1:1 with  $V_{CC}$ . The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input signal.

**Table 5. 100EP DC CHARACTERISTICS, PECL** ( $V_{CC} = 5.0\text{ V}$ ,  $V_{EE} = 0\text{ V}$  (Note 1))

| Symbol      | Characteristic   | -40°C |      |      | 25°C |      |      | 85°C |      |      | Unit          |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
|             |  | Min   | Typ  | Max  | Min  | Typ  | Max  | Min  | Typ  | Max  |               |
| $I_{EE}$    | Power Supply Current   | 22    | 28   | 36   | 24   | 30   | 40   | 26   | 32   | 42   | mA            |
| $V_{OH}$    | Output HIGH Voltage (Note 2)   | 3855  | 3980 | 4105 | 3855 | 3980 | 4105 | 3855 | 3980 | 4105 | mV            |
| $V_{OL}$    | Output LOW Voltage (Note 2)  | 3005  | 3180 | 3355 | 3005 | 3180 | 3355 | 3005 | 3180 | 3355 | mV            |
| $V_{IH}$    | Input HIGH Voltage (Single-Ended)  | 3775  |      | 4120 | 3775 |      | 4120 | 3775 |      | 4120 | mV            |
| $V_{IL}$    | Input LOW Voltage (Single-Ended)   | 3055  |      | 3375 | 3055 |      | 3375 | 3055 |      | 3375 | mV            |
| $V_{BB}$    | Output Voltage Reference   | 3475  | 3575 | 3675 | 3475 | 3575 | 3675 | 3475 | 3575 | 3675 | mV            |
| $V_{IHCMR}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0   |      | 5.0  | 2.0  |      | 5.0  | 2.0  |      | 5.0  | V             |
| $I_{IH}$    | Input HIGH Current   |       |      | 150  |      |      | 150  |      |      | 150  | $\mu\text{A}$ |
| $I_{IL}$    | Input LOW Current  | 0.5   |      |      | 0.5  |      |      | 0.5  |      |      | $\mu\text{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with  $V_{CC}$ .  $V_{EE}$  can vary +2.0 V to -0.5 V.
2. All loading with 50  $\Omega$  to  $V_{CC} - 2.0\text{ V}$ .
3.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ .  $V_{IHCMR}$  max varies 1:1 with  $V_{CC}$ . The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input signal.

# MC100EP16VA

**Table 6. 100EP DC CHARACTERISTICS, NECL** ( $V_{CC} = 0\text{ V}$ ;  $V_{EE} = -5.5\text{ V}$  to  $-3.0\text{ V}$  (Note 1))

| Symbol      | Characteristic   | -40°C        |       |       | 25°C         |       |       | 85°C         |       |       | Unit          |
|-------------|--|--------------|-------|-------|--------------|-------|-------|--------------|-------|-------|---------------|
|             |  | Min          | Typ   | Max   | Min          | Typ   | Max   | Min          | Typ   | Max   |               |
| $I_{EE}$    | Power Supply Current   | 22           | 28    | 36    | 24           | 30    | 40    | 26           | 32    | 42    | mA            |
| $V_{OH}$    | Output HIGH Voltage (Note 2)   | -1145        | -1020 | -895  | -1145        | -1020 | -895  | -1145        | -1020 | -895  | mV            |
| $V_{OL}$    | Output LOW Voltage (Note 2)  | -1995        | -1870 | -1745 | -1995        | -1870 | -1745 | -1995        | -1870 | -1745 | mV            |
| $V_{IH}$    | Input HIGH Voltage (Single-Ended)  | -1225        |       | -880  | -1225        |       | -880  | -1225        |       | -880  | mV            |
| $V_{IL}$    | Input LOW Voltage (Single-Ended)   | -1945        |       | -1625 | -1945        |       | -1625 | -1945        |       | -1625 | mV            |
| $V_{BB}$    | Output Voltage Reference   | -1525        | -1425 | -1325 | -1525        | -1425 | -1325 | -1525        | -1425 | -1325 | mV            |
| $V_{IHCMR}$ | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | $V_{EE}+2.0$ |       | 0.0   | $V_{EE}+2.0$ |       | 0.0   | $V_{EE}+2.0$ |       | 0.0   | V             |
| $I_{IH}$    | Input HIGH Current   |              |       | 150   |              |       | 150   |              |       | 150   | $\mu\text{A}$ |
| $I_{IL}$    | Input LOW Current  | 0.5          |       |       | 0.5          |       |       | 0.5          |       |       | $\mu\text{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with  $V_{CC}$ .
2. All loading with 50  $\Omega$  to  $V_{CC} - 2.0\text{ V}$ .
3.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ ,  $V_{IHCMR}$  max varies 1:1 with  $V_{CC}$ . The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input signal.

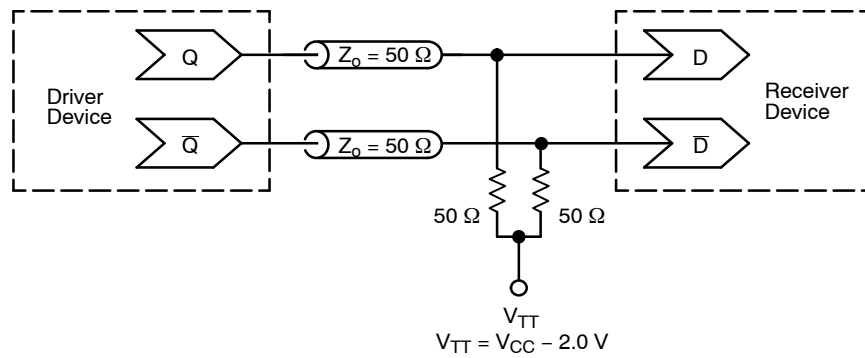
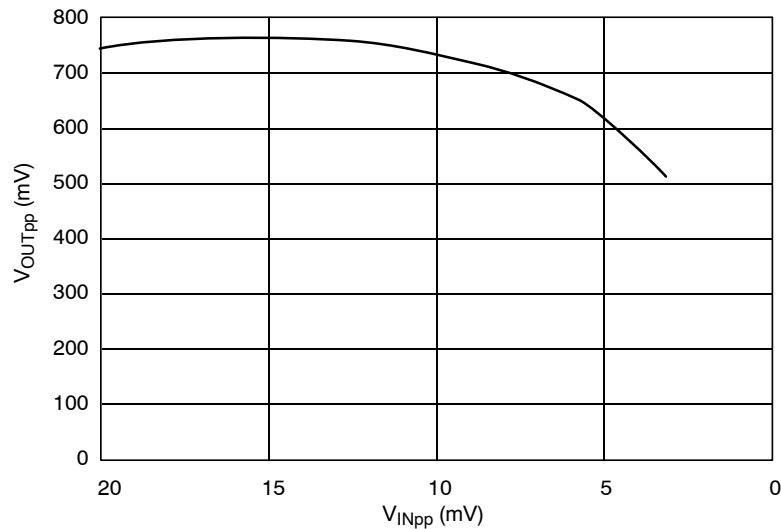
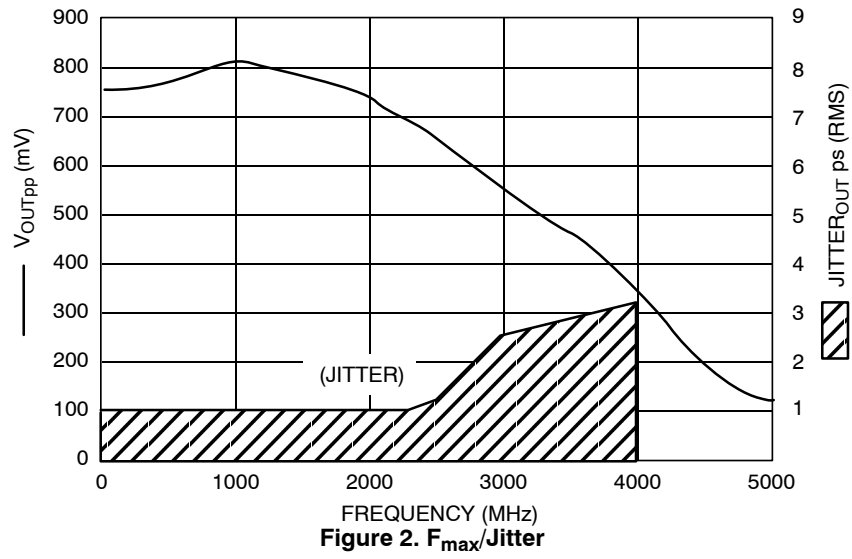
**Table 7. AC CHARACTERISTICS** ( $V_{CC} = 0\text{ V}$ ;  $V_{EE} = -3.0\text{ V}$  to  $-5.5\text{ V}$  or  $V_{CC} = 3.0\text{ V}$  to  $5.5\text{ V}$ ;  $V_{EE} = 0\text{ V}$  (Note 1))

| Symbol                   | Characteristic  | -40°C |     |      | 25°C |     |      | 85°C |     |      | Unit |
|--------------------------|---|-------|-----|------|------|-----|------|------|-----|------|------|
|                          |   | Min   | Typ | Max  | Min  | Typ | Max  | Min  | Typ | Max  |      |
| $f_{\max}$               | Maximum Frequency (See Figure 2 $F_{\max}/\text{JITTER}$ )      |       | > 3 |      |      | > 3 |      |      | > 3 |      | GHz  |
| $t_{PLH}$ ,<br>$t_{PHL}$ | Propagation Delay to Output Differential                        | 200   | 260 | 320  | 220  | 270 | 340  | 250  | 320 | 390  | ps   |
| $t_{SKEW}$               | Duty Cycle Skew (Note 2)  |       | 5.0 | 20   |      | 5.0 | 20   |      | 5.0 | 20   | ps   |
| $t_{JITTER}$             | Cycle-to-Cycle Jitter (See Figure 2 $F_{\max}/\text{JITTER}$ )  |       | 0.2 | < 1  |      | 0.2 | < 1  |      | 0.2 | < 1  | ps   |
| $V_{PP}$                 | Input Voltage Swing (Differential Configuration) (See Figure 3) | 20    | 800 | 1200 | 20   | 800 | 1200 | 20   | 800 | 1200 | mV   |
| $t_r$ ,<br>$t_f$         | Output Rise/Fall Times Q, Q (20% – 80%)                         | 70    | 110 | 170  | 80   | 110 | 180  | 80   | 120 | 200  | ps   |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50  $\Omega$  to  $V_{CC}-2.0\text{ V}$ .
2. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

# MC100EP16VA



**Figure 4. Typical Termination for Output Driver and Device Evaluation**  
(See Application Note [AND8020/D](#) – Termination of ECL Logic Devices)

## Resource Reference of Application Notes

- AN1405/D** – ECL Clock Distribution Techniques
- AN1406/D** – Designing with PECL (ECL at +5.0 V)
- AN1503/D** – ECLinPS™ I/O SPiCE Modeling Kit
- AN1504/D** – Metastability and the ECLinPS Family
- AN1568/D** – Interfacing Between LVDS and ECL
- AN1672/D** – The ECL Translator Guide
- AND8001/D** – Odd Number Counters Design
- AND8002/D** – Marking and Date Codes
- AND8020/D** – Termination of ECL Logic Devices
- AND8066/D** – Interfacing with ECLinPS
- AND8090/D** – AC Characteristics of ECL Devices

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

DATE 16 FEB 2011



## NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

## GENERIC MARKING DIAGRAM\*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

## STYLES ON PAGE 2

|                  |             |  |
|------------------|-------------|--|
| DOCUMENT NUMBER: | 98ASB42564B | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION:     | SOIC-8 NB   | PAGE 1 OF 2  |

onsemi and onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

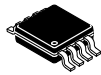
|   |  |  |  |
|---|--|--|--|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER   | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE   |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE   | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE  | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND  | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1   | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN   |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN  | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN   | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC  | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE   | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1   | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6  | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT   | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC  | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN  | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN  |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |  |  |

|                         |                    |   |
|-------------------------|--------------------|---|
| <b>DOCUMENT NUMBER:</b> | <b>98ASB42564B</b> | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| <b>DESCRIPTION:</b>     | <b>SOIC-8 NB</b>   | <b>PAGE 2 OF 2</b>  |

**onsemi** and **onsemi** are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

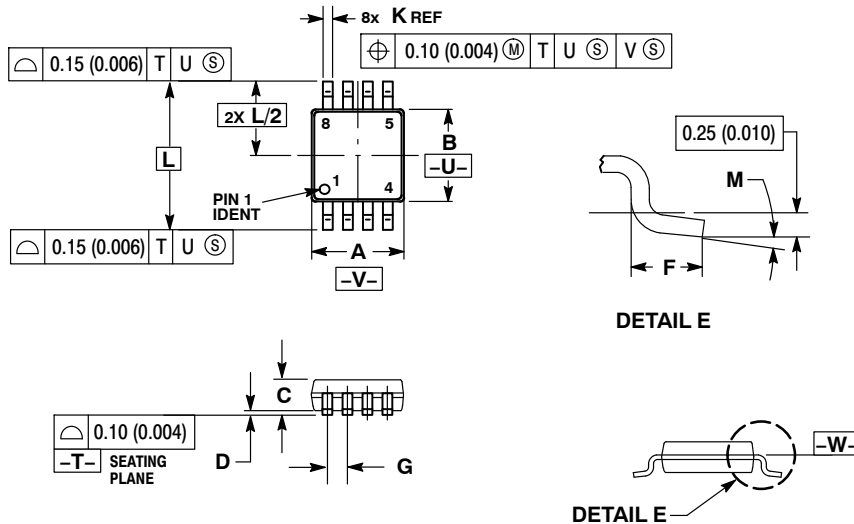
ON Semiconductor®



SCALE 2:1

## TSSOP 8 CASE 948R-02 ISSUE A

DATE 04/07/2000



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 2.90        | 3.10 | 0.114     | 0.122 |
| B   | 2.90        | 3.10 | 0.114     | 0.122 |
| C   | 0.80        | 1.10 | 0.031     | 0.043 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.40        | 0.70 | 0.016     | 0.028 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| K   | 0.25        | 0.40 | 0.010     | 0.016 |
| L   | 4.90 BSC    |      | 0.193 BSC |       |
| M   | 0°          | 6°   | 0°        | 6°    |

DOCUMENT NUMBER: 98AON00236D

Electronic versions are uncontrolled except when accessed directly from the Document Repository.  
Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: TSSOP 8

PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Email Requests to: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**onsemi Website:** [www.onsemi.com](http://www.onsemi.com)

### TECHNICAL SUPPORT

**North American Technical Support:**

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

**Europe, Middle East and Africa Technical Support:**

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[onsemi:](#)

[MC100EP16VADG](#) [MC100EP16VADTG](#) [MC100EP16VADTR2G](#)